

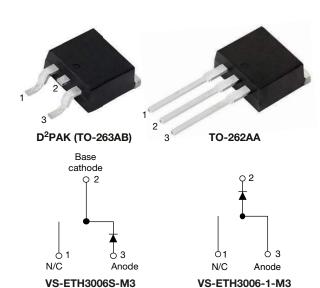
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Vishay Semiconductors

HALOGEN

FREE

Hyperfast Rectifier, 30 A FRED Pt®



| PRIMARY CHARACTERISTICS | | | | | | | |
|----------------------------------|---|--|--|--|--|--|--|
| I _{F(AV)} 30 A | | | | | | | |
| V _R | 600 V | | | | | | |
| V _F at I _F | 1.4 V | | | | | | |
| t _{rr} (typ.) | 27 ns | | | | | | |
| T _J max. | 175 °C | | | | | | |
| Package | D ² PAK (TO-263AB), TO-262AA | | | | | | |
| Circuit configuration | Single | | | | | | |

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified according to JEDEC®-JESD 47
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION/APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|---|--------------------|------------------------|-------------|-------|--|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | | | | |
| Repetitive peak reverse voltage | V_{RRM} | | 600 | V | | | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 95 °C | 30 | ۸ | | | | | |
| Non-repetitive peak surge current | I _{FSM} | T _C = 25 °C | 180 | A | | | | | |
| Operating junction and storage temperatures | T_J , T_{Stg} | | -65 to +175 | °C | | | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|--|-------------------------------------|--|------|-------|------|----|--|--|--|
| PARAMETER | MIN. | TYP. | MAX. | UNITS | | | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | Ι _R = 100 μΑ | 600 | - | - | | | | |
| Forward voltage | V _F | I _F = 30 A | ı | 2.0 | 2.65 | V | | | |
| r orward vortage | | I _F = 30 A, T _J = 150 °C | ı | 1.4 | 1.8 | | | | |
| Reverse leakage current | I _R | $V_R = V_R$ rated | - | 0.02 | 30 | | | | |
| neverse leakage current | | $T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | - | 50 | 300 | μA | | | |
| Junction capacitance | C _T | V _R = 600 V | - | 20 | - | pF | | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH | | | |

VS-ETH3006S-M3, VS-ETH3006-1-M3

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| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|---|------------------|---------------------------|---|------|------|------|-----------|--|--|
| PARAMETER | SYMBOL | TEST (| CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| | | $I_F = 1 A, dI_F/dt = 50$ | $I_F = 1 \text{ A, } dI_F/dt = 50 \text{ A/}\mu\text{s, } V_R = 30 \text{ V}$ | | | 35 | | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 26 | - | ns - A | | |
| | | T _J = 125 °C | I _F = 30 A dI _F /dt = 200 A/μs V _B = 200 V | - | 70 | - | | | |
| Dools we consent our went | I _{RRM} | T _J = 25 °C | | - | 3.5 | - | | | |
| Peak recovery current | | T _J = 125 °C | | - | 7.6 | - | | | |
| Reverse recovery charge | 0 | T _J = 25 °C | "" | - | 50 | - | | | |
| | Q_{rr} | T _J = 125 °C | | - | 280 | - | nC | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | |
|--|-----------------------------------|---|-----------|----------|------------|------------------------|--|--|--|
| PARAMETER | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | | | |
| Thermal resistance, junction-to-case | R _{thJC} | | ı | 0.95 | 1.4 | °C/W | | | |
| Thermal resistance, junction-to-ambient | R _{thJA} | Typical socket mount | - | - | 70 | | | | |
| Thermal resistance, case-to-heatsink | R _{thCS} | Mounting surface, flat, smooth, and greased | - | 0.5 | - | | | | |
| Weight | | | - | 2.0 | - | g | | | |
| vveigni | | | = | 0.07 | - | OZ. | | | |
| Mounting torque | | | 6 (5) | - | 12 (10) | kgf · cm (lbf · in) | | | |
| Marking daying | | Case style D ² PAK (TO-263AB) | | ETH3006S | | | | | |
| Marking device | | Case style TO-262AA | ETH3006-1 | | | | | | |

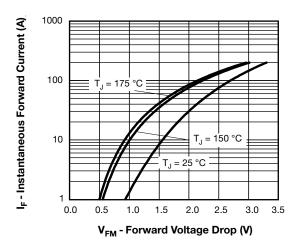


Fig. 1 - Typical Forward Voltage Drop Characteristics

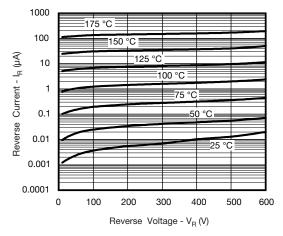


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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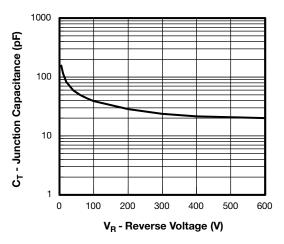


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

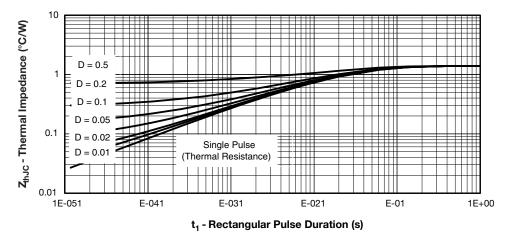


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

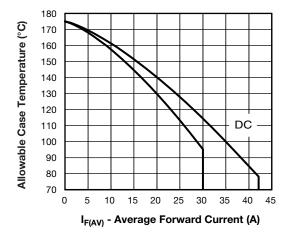


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

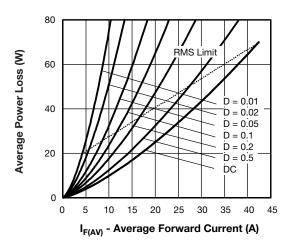
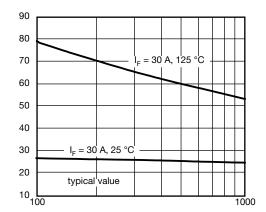


Fig. 6 - Forward Power Loss Characteristics

t_{rr} (ns)

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dl_F/dt (A/µs) Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

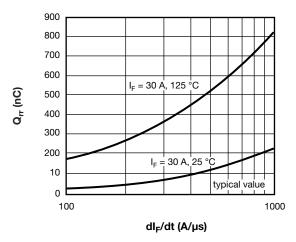
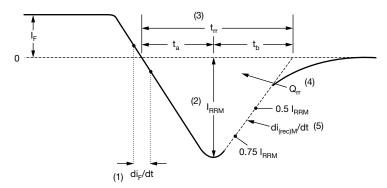


Fig. 8 - Typical Stored Charge vs. dl_E/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current

1000

- (3) \mathbf{t}_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

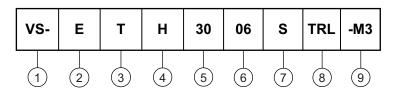
Fig. 9 - Reverse Recovery Waveform and Definitions

VS-ETH3006S-M3, VS-ETH3006-1-M3

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ORDERING INFORMATION TABLE

Device code



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Circuit configuration

E = single

T = TO-220

4 5 H = hyperfast recovery time

Current code (30 = 30 A)

Voltage code (06 = 600 V)

• $S = D^2PAK (TO-263AB)$

• -1 = TO-262AA

8 • None = tube (50 pieces)

• TRL = tape and reel (left oriented, for D²PAK (TO-263AB) package)

• TRR = tape and reel (right oriented, for D²PAK (TO-263AB) package)

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free 9

| ORDERING INFORMATION (Example) | | | | | | | | |
|---|-----|------------------------------------|--|--|--|--|--|--|
| PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION | | | | | | | | |
| VS-ETH3006S-M3 | 50 | Antistatic plastic tubes | | | | | | |
| VS-ETH3006STRR-M3 | 800 | 13" diameter plastic tape and reel | | | | | | |
| VS-ETH3006STRL-M3 | 800 | 13" diameter plastic tape and reel | | | | | | |
| VS-ETH3006-1-M3 | 50 | Antistatic plastic tubes | | | | | | |

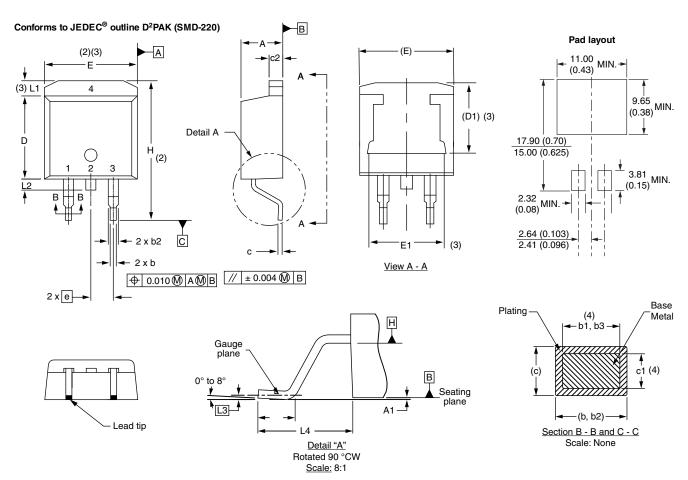
| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|-------------------------------|--------------------------|--|--|--|--|
| Dimensions | D ² PAK (TO-263AB) | www.vishay.com/doc?96164 | | | | |
| Dimensions | TO-262AA | www.vishay.com/doc?96165 | | | | |
| Dout moulting information | D ² PAK (TO-263AB) | www.vishay.com/doc?95444 | | | | |
| Part marking information | TO-262AA | www.vishay.com/doc?95443 | | | | |
| Packaging information | D ² PAK (TO-263AB) | www.vishay.com/doc?96424 | | | | |



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D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIM | ETERS | INC | HES | NOTES | | SYMBOL | | ETERS | INC | HES | NOTES |
|---------|--------|-------|-------|-------|-------|-------|---------|-------|-------|-------|-------|-------|
| STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES | NOTES | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | | E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | е | 2.54 | BSC | 0.100 | BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164

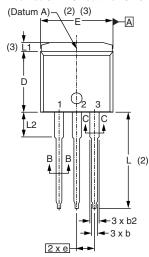


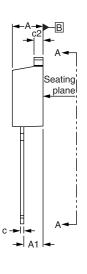
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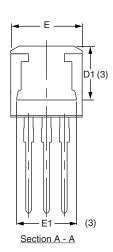
TO-262AA

DIMENSIONS in millimeters and inches

Modified JEDEC® outline TO-262







⊕ 0.010 **M** A**M** B

Lead assignments

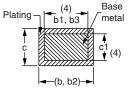


Diodes

1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

| SYMBOL | MILLIN | ETERS | INC | INCHES | | | |
|---------|----------|-------|-------|--------|-------|--|--|
| STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES | | |
| А | 4.06 | 4.83 | 0.160 | 0.190 | | | |
| A1 | 2.03 | 3.02 | 0.080 | 0.119 | | | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 | | |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 | | |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 | | |
| е | 2.54 BSC | | 0.100 |) BSC | | | |
| L | 13.46 | 14.10 | 0.530 | 0.555 | | | |
| L1 | - | 1.65 | - | 0.065 | 3 | | |
| L2 | 3.56 | 3.71 | 0.140 | 0.146 | | | |

Notes

(4) Dimension b1 and c1 apply to base metal only

Controlling dimension: inches

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



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